TOSHIBA

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

## **HN3C02F**

TV TUNER, UHF OSCILLATOR APPLICATION. TV TUNER, UHF CONVERTER APPLICATION.

- Including Two Devices in SM6 (Super Mini Type with 6Leads)
- High Transition Frequency: fT=2400MHz (Typ.)

## MAXIMUM RATINGS (Ta = $25^{\circ}$ C) (Q<sub>1</sub>, Q<sub>2</sub>)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{\mathrm{CBO}}$	30	V
Collector-Emitter Voltage	VCEO	15	V
Emitter-Base Voltage	$V_{\rm EBO}$	3	V
Collector Current	IC	50	mA
Base Current	IB	25	mA
Collector Power Dissipation	PC*	300	mW
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

Total

## ELECTRICAL CHARACTERISTICS ( $Ta = 25^{\circ}C$ ) ( $Q_1, Q_2$ )

Unit in mm
2.8 + 0.2 2.8 - 0.3 + 0.2 1.6 - 0.1 6 1 1 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
3 4 9 10 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
1. COLLECTOR 1 (C1) 2 2 EMITTER 1 (E1)
2. EMITTER 1 (E1) • 3. COLLECTOR 2 (C2)
2. EMITTER 1 (E1) 5   3. COLLECTOR 2 (C2) 4. EMITTER 2 (E2)
5. BASE 2 (B2)
6. BASE 1 (B1)
JEDEC —
EIAJ —
TOSHIBA 2-3N1B

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 30V, I_{E} = 0$	_	_	0.1	$\mu$ <b>A</b>
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=2V, I_C=0$	_	_	1.0	$\mu$ <b>A</b>
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	$I_C=1mA$ , $I_B=0$	15	_		V
DC Current Gain	$h_{ extbf{FE}}$	$V_{CE}=10V, I_{E}=5mA$	40	_	200	_
Transition Frequency	$ m f_{T}$	$V_{CE} = 10V, I_{C} = 2mA, f = 800MHz$	1500	2400	1	MHz
Reverse Transfer Capacitance Q <sub>1</sub>	$C_{re(1)}$	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	0.53	0.85	рF
Reverse Transfer Capacitance Q <sub>2</sub>	C <sub>re (2)</sub>	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	0.48	0.80	pF
Collector-Base Time Constant Q <sub>1</sub>	C <sub>c</sub> ·r <sub>bb</sub> ' (1)	$V_{\text{CB}} = 10\text{V}, I_{\text{C}} = 2\text{mA}, \\ f = 30\text{MHz}$	_	15.0	22.0	ps
Collector-Base Time Constant Q2	$C_{c} \cdot r_{bb} \cdot (2)$	V <sub>CB</sub> =10V, I <sub>C</sub> =2mA, f=30MHz	_	14.5	21.5	ps

PIN ASSIGNMENT (TOP VIEW)

**MARKING** 



5 4 TYPE NAME 1 2 3

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